UNITED STATES
SECURITIES AND EXCHANGE COMMISSION
Washington, D.C. 20549

FORM 8-K

CURRENT REPORT
Pursuant to Section 13 or 15(d) of the Securities Exchange Act of 1934

June 4, 2010
Date of Report (Date of earliest event reported)

DIODES INCORPORATED

(Exact name of registrant as specified in its charter)

Delaware	**002-25577**	**95-2039518**
(State or other jurisdiction of incorporation)	(Commission File Number)	(I.R.S. Employer Identification No.)

15660 Dallas Parkway, Suite 850 **Dallas, Texas**	**75248**
(Address of principal executive offices)	(Zip Code)

(972) 385-2810
(Registrant's telephone number, including area code)

Check the appropriate box below if the Form 8-K filing is intended to simultaneously satisfy the filing obligation of the registrant under any of the following provisions:

o Written communications pursuant to Rule 425 under the Securities Act (17 CFR 230.425)

o Soliciting material pursuant to Rule 14a-12 under the Exchange Act (17 CFR 240.14a-12)

o Pre-commencement communications pursuant to Rule 14d-2(b) under the Exchange Act (17 CFR 240.14d-2(b))

o Pre-commencement communications pursuant to Rule 13e-4(c) under the Exchange Act (17 CFR 240.13e-4(c))

Item 7.01. Regulation FD Disclosure.

On June 4, 2010, Diodes Incorporated (the "Company") issued a press release, announcing its expansion into a new semiconductor category with its first standard logic product family. A copy of the press release is attached as Exhibit 99.1 to this Report.

On June 8, 2010, the Company issued a press release to update its guidance for the second quarter of 2010. A copy of the press release is attached as Exhibit 99.2 to this Report.

On June 9, 2010, Dr. Keh-Shew Lu, the Company's President and Chief Executive Officer, and Carl Wertz, the Company's Vice President of Finance and Investor Relations, held a presentation at the UBS Global Technology and Services Conference. A copy of the presentation slides is attached as Exhibit 99.3 to this Report.

The information in this Item 7.01, including Exhibit 99.1, Exhibit 99.2 and Exhibit 99.3, will not be treated as filed for the purposes of Section 18 of the Securities Exchange Act of 1934 (the "Exchange Act") or otherwise subject to the liabilities of that section. This information will not be incorporated by reference into a filing under the Securities Act of 1933, or into another filing under the Exchange Act, unless that filing expressly refers to specific information in this Report. The furnishing of the information in this Item 7.01 is not intended to, and does not, constitute a representation that such furnishing is required by Regulation FD or that the information in this Item 7.01 is material information that is not otherwise publicly available.

In the presentation slides, attached as Exhibit 99.3, the Company utilized financial measures and terms not calculated in accordance with accounting principles generally accepted in the United States ("GAAP") in order to provide stockholders with an alternative method for assessing its operating results in a manner that enables stockholders to more thoroughly evaluate its current performance as compared to past performance. The Company also believes these non-GAAP measures provide stockholders with a more informed baseline for modeling its future financial performance. The Company's management uses these non-GAAP measures for the same purpose. The Company believes that its stockholders should have access to the same set of tools that it uses in analyzing its results. These non-GAAP measures should be considered in addition to results prepared in accordance with GAAP, but should not be considered a substitute for or superior to GAAP results. See Exhibit 99.1 to the Company's Form 8-K, filed on May 11, 2010, for definitions of the non-GAAP financial measures, together with an explanation of why management uses these measures and why management believes that these non-GAAP financial measures are useful to stockholders. In addition, in Exhibit 99.1 to the Company's Form 8-K, filed on May 11, 2010, it has provided tables to reconcile the non-GAAP financial measures utilized to GAAP financial measures.

Cautionary Information Regarding Forward-Looking Statements

Except for the historical and factual information contained in the press release and presentation slides attached as Exhibit 99.2 and Exhibit 99.3, respectively, to this Report, the matters set forth in such press release and presentation slides are forward-looking statements within the meaning of the "safe harbor" provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements are subject to risks and uncertainties that may cause actual results to differ materially, including, but are not limited to, such factors as the Company's business and growth strategy; the introduction and market reception to new product announcements; fluctuations in product demand and supply; prospects for the global economy; the Company's ability to continue to introduce new products; the Company's ability to maintain customer and vendor relationships; technological advancements; impact of competitive products and pricing; growth in targeted markets; successful integration of acquired companies and/or assets; the Company's ability to successfully make additional acquisitions; risks of domestic and foreign operations; currency exchange rates; availability of tax credits; the Company's ability to maintain its current growth strategy or continue to maintain its current performance and loadings in the manufacturing facilities; the global economic weakness may be more severe or last longer than the Company currently anticipates; and other information detailed from time to time in the Company's filings with the United States Securities and Exchange Commission. You should not place undue reliance on these forward-looking statements, which speak only as of the date of the press release and presentation slides. The Company undertakes no obligation to update publicly any forward-looking statements, whether as a result of new information, future events or otherwise.

Item 9.01. Financial Statements and Exhibits.

(d) Exhibits

Exhibit Number	Description
99.1	Press release dated June 4, 2010
99.2	Press release dated June 8, 2010
99.3	Presentation slides for the presentation at the UBS Global Technology and Services Conference on June 9, 2010

SIGNATURES

Pursuant to the requirements of the Securities Exchange Act of 1934, the Registrant has duly caused this report to be signed on its behalf by the undersigned hereunto duly authorized.

Dated: June 9, 2010

DIODES INCORPORATED

By /s/ Richard D. White
RICHARD D. WHITE,
Chief Financial Officer

Exhibit 99.1

Diodes Incorporated Announces Logic Products that Provide Upgrade for Industry Standard Parts

Diodes Incorporated expands into a new semiconductor category with its first standard logic product family

Dallas, Texas —June 4, 2010 —— Diodes Incorporated (Nasdaq: DIOD), a leading global manufacturer and supplier of high-quality application specific standard products within the broad discrete and analog semiconductor markets, today has released its very first family of single-gate logic products. Built on an advanced 5V CMOS process and offering performance enhancements over existing alternatives, the 74LVC1Gxx series provides users with the eight most popular standard logic functions in SOT25 and SOT353 package options, and the 74LVCE1GXX series offers enhanced performance versions of these same functions.

Dr. Keh-Shew Lu, President and Chief Executive Officer of Diodes Incorporated said, “I’m pleased to announce Diodes’ entry into the standard logic market. The logic market represents a natural fit for Diodes’ strategic focus on high-volume standard products, and expands our serviceable available market by over 15% to an approximate $20 billion annual SAM. Furthermore, there are strong packaging synergies with our existing Analog and Discrete product lines. Many current logic suppliers are dependent on packaging subcontractors, and customers are seeing extended industry leadtimes on these products. Diodes has its own world-class cost-effective, high-volume assembly facility that’s well suited to the manufacture of low pin-count SOT25 and SOT353 packages. We’re pleased to be able to leverage this capability to provide users with an alternative source of quality, high-performance logic products.”

Suitable for use in a variety of communication, computing, consumer and networking equipment, the initial Logic product offering covers AND, NAND, OR, NOR, XOR, inversion and buffering functions. The single-gate products are cost effective replacements for industry standard parts in point-of-application general purpose logic, level shifting and signal isolation applications.

At 1.65V to 5.5V, the operating voltage range of the 74LVC1Gxx series is wide, enabling it to support both portable battery operated and traditional 5V applications. To address higher performance application requirements, the 74LVCE1Gxx extended specification products operate down to 1.4V, and provide a 30% enhancement in switching speeds at 1.8V as compared to the standard LVC family. Both families have 5.5V tolerant inputs, enabling the creation of voltage translation solutions.

In many applications, the logic products will draw less than 1µA of supply current, ensuring low power consumption. Their I_{OFF} output circuitry means that the output is disabled when the device is powered down, preventing damaging backflow current from entering the device or unnecessarily loading shared signal lines. Further information is available on the Company’s website at www.diodes.com/logic.

About Diodes Incorporated

Diodes Incorporated (Nasdaq: DIOD), a Standard and Poor’s SmallCap 600 and Russell 3000 Index company, is a leading global manufacturer and supplier of high-quality application specific standard products within the broad discrete, logic, and analog semiconductor markets. Diodes serves the consumer electronics, computing, communications, industrial, and automotive markets. Diodes’ products include diodes, rectifiers, transistors, MOSFETs, protection devices, functional specific arrays, single gate logic, amplifiers and comparators, Hall-effect and temperature sensors; power management devices, including LED drivers, DC-DC switching and linear voltage regulators, and voltage references along with special function devices, such as USB power switches, load switches, voltage supervisors, and motor controllers. The Company’s corporate headquarters, logistics center, and Americas’ sales office are located in Dallas, Texas. Design, marketing, and engineering centers are located in Dallas; San Jose, California; Taipei, Taiwan; Manchester, England; and Neuhaus, Germany. The Company’s wafer fabrication facilities are located in Kansas City, Missouri and Manchester, with two manufacturing facilities located in Shanghai, China, another in Neuhaus, and a joint venture facility located in Chengdu, China. Additional engineering, sales, warehouse, and logistics offices are located in Taipei; Hong Kong; Manchester; and Munich, Germany; with support offices located throughout the world. For further information, including SEC filings, visit the Company’s website at http://www.diodes.com.

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Exhibit 99.2

Diodes Incorporated Increases Second Quarter 2010 Guidance

Dallas, Texas — June 8, 2010 — Diodes Incorporated (Nasdaq: DIOD), a leading global manufacturer and supplier of high-quality application specific standard products within the broad discrete, logic and analog semiconductor markets, today increased its revenue and gross margin guidance for the second quarter of 2010.

The Company is increasing its revenue guidance for the second quarter of 2010 due to increasing demand for the Company's products in its worldwide markets. Revenue is expected to range between $147 million and $151 million, an increase of 7.5 to 10.5 percent sequentially, compared to its previous guidance of $143 million to $148 million or an increase of 4 to 8 percent sequentially. The Company is also raising its second quarter 2010 gross margin guidance due to gross profit growing faster than the revenue increase. Gross margin is expected to range between 35.0 to 36.0 percent versus its prior guidance of gross profit growing at the same rate as revenue, or gross margin of 34.9 percent.

About Diodes Incorporated

Diodes Incorporated (Nasdaq: DIOD), a Standard and Poor's SmallCap 600 and Russell 3000 Index company, is a leading global manufacturer and supplier of high-quality application specific standard products within the broad discrete, logic, and analog semiconductor markets. Diodes serves the consumer electronics, computing, communications, industrial, and automotive markets. Diodes' products include diodes, rectifiers, transistors, MOSFETs, protection devices, functional specific arrays, single gate logic, amplifiers and comparators, Hall-effect and temperature sensors; power management devices, including LED drivers, DC-DC switching and linear voltage regulators, and voltage references along with special function devices, such as USB power switches, load switches, voltage supervisors, and motor controllers. The Company's corporate headquarters, logistics center, and Americas' sales office are located in Dallas, Texas. Design, marketing, and engineering centers are located in Dallas; San Jose, California; Taipei, Taiwan; Manchester, England; and Neuhaus, Germany. The Company's wafer fabrication facilities are located in Kansas City, Missouri and Manchester, with two manufacturing facilities located in Shanghai, China, another in Neuhaus, and a joint venture facility located in Chengdu, China. Additional engineering, sales, warehouse, and logistics offices are located in Taipei; Hong Kong; Manchester; and Munich, Germany; with support offices located throughout the world. For further information, including SEC filings, visit the Company's website at http://www.diodes.com.

Safe Harbor Statement Under the Private Securities Litigation Reform Act of 1995: Any statements set forth above that are not historical facts are forward-looking statements that involve risks and uncertainties that could cause actual results to differ materially from those in the forward-looking statements. Such statements include statements regarding our expectation that: the Company is increasing its revenue guidance for the second quarter of 2010 due to increasing demand for the Company's products in its worldwide markets; revenue is expected to range between $147 million and $151 million, an increase of 7.5 to 10.5 percent sequentially, compared to its previous guidance of $143 million to $148 million or an increase of 4 to 8 percent sequentially; the Company is also raising its second quarter 2010 gross margin guidance due to gross profit growing faster than the revenue increase; and gross margin is expected to range between 35.0 to 36.0 percent versus its prior guidance of gross profit growing at the same rate as revenue or gross margin of 34.9 percent. Potential risks and uncertainties include, but are not limited to, such factors as: we may not be able to maintain our current growth strategy or continue to maintain our current performance and loadings in our manufacturing facilities; our future guidance may be incorrect; the global economic weakness may be more severe or last longer than we currently anticipate; and other information detailed from time to time in the Company's filings with the United States Securities and Exchange Commission.

Recent news releases, annual reports, and SEC filings are available at the Company's website: http://www.diodes.com. Written requests may be sent directly to the Company, or they may be e-mailed to: diodes-fin@diodes.com.

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Exhibit 99.3

DIODES INCORPORATED

UBS Global Technology Conference
New York
June 9, 2010

Safe Harbor Statement

Any statements set forth herein that are not historical facts are forward-looking statements that involve risks and uncertainties that could cause actual results to differ materially from those in the forward-looking statements. Such forward-looking statements include, but are not limited to, statements regarding Diodes' business objective, revenue and gross margin guidance, future quarterly outlook, growth strategy and guidance in revenue range, revenue growth, gross margin, gross profit, gross profit growth, operating expenses, income tax rate range, the number of outstanding shares of Common Stock, and the rate of capital expenditure.

Potential risks and uncertainties include, but are not limited to, such factors as Diodes' business and growth strategy; the introduction and market reception to new product announcements; fluctuations in product demand and supply; prospects for the global economy; continued introduction of new products; Diodes' ability to maintain customer and vendor relationships; technological advancements; impact of competitive products and pricing; growth in targeted markets; successful integration of acquired companies and/or assets; Diodes' ability to successfully make additional acquisitions; risks of domestic and foreign operations; currency exchange rates; availability of tax credits; Diodes' ability to maintain our current growth strategy or continue to maintain our current performance and loadings in our manufacturing facilities; the global economic weakness may be more severe or last longer than we currently anticipate; and other information detailed from time to time in Diodes' filings with the United States Securities and Exchange Commission.

This presentation also contains non-GAAP measures. See the Company's press release on May 6, 2010 titled "Diodes Incorporated Reports First Quarter 2010 Financial Results" for detailed information related to the Company's non-GAAP measures and a reconciliation of GAAP net income (loss) to non-GAAP net income (loss).

Management Representative

Dr. Keh-Shew Lu

President and CEO

President and CEO	Since 2005
Director – Diodes	9 years
Texas Instruments	27 years

Experience:

- Senior Vice President of TI Worldwide Analog and Logic
- Senior Vice President of TI Worldwide Memory
- President of Texas Instruments – Asia

Education:

- Master's Degree and Doctorate in Electrical Engineering Texas Tech University
- Bachelor's Degree in Engineering
- National Cheng Kung University - Taiwan

DIODES INCORPORATED

About Diodes

A leading global manufacturer and supplier of high-quality **application specific, standard products** within the broad discrete, logic and analog markets, serving the **computing, consumer, communications,** industrial and automotive segments.

Business Objective

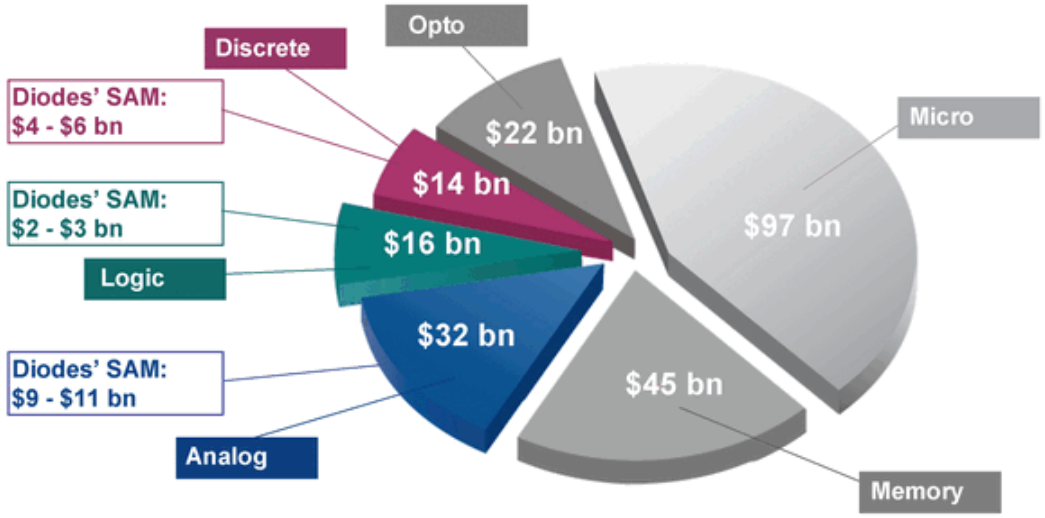
To consistently achieve above-market **profitable growth**, utilizing our innovative and cost-effective **packaging** technology, suited for **high volume, high growth** markets by leveraging process expertise and design excellence to deliver market-leading semiconductor products

DIODES INCORPORATED

Diodes Strategy: Profitable Growth

Significant Market Opportunity

2009 Total Semiconductor Market ($226 bn)



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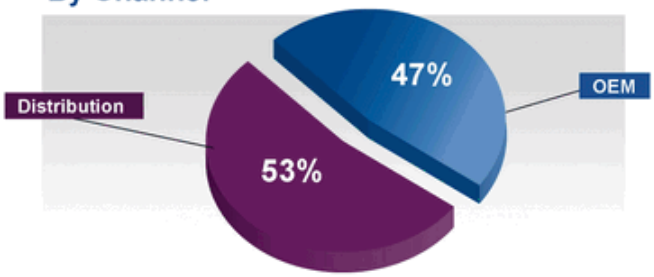
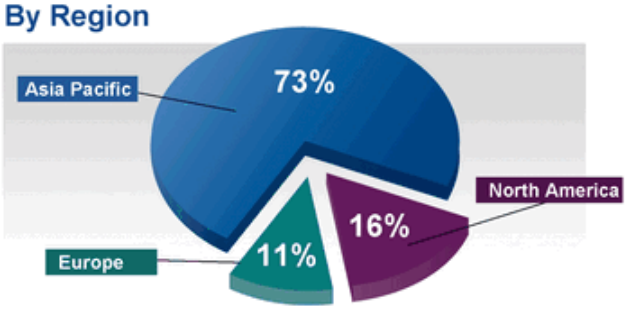
Revenue Profile – 1Q10

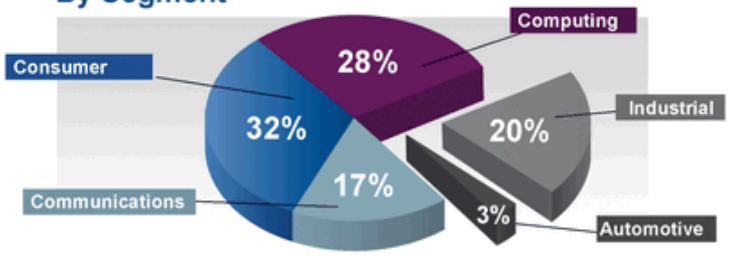
By Channel



By Region



By Segment



DIODES INCORPORATED

Efficiency, Functionality, and Control for Smart Phones

- **LCD Backlighting**
  - LED Drivers
  - Boost Converters
  - Schottky Diodes
- **LED Flash Module**
  - Camera Flash Drivers
  - ZXMN series MOSFETs
- **LCD / OLED Display Bias**
  - LCD Bias ICs
  - OLED Bias ICs
  - Schottky Diodes
- **Battery Power Management**
  - USB Power Switches
  - Current Monitors
  - Charger ICs
  - Low-Saturation Bipolar Transistors
  - ZXMP series MOSFETs

- **GPS Antenna Detection**
  - Current Monitors
- **RF Power Amplifier**
  - Low Dropout Regulators
- **System Voltage Conversion**
  - Low Dropout Regulators
  - DC-DC Converters
  - Schottky Diodes
  - Low-Saturation Bipolar Transistors
- **Flip / Slide Detection**
  - Hall Effect Sensors
  - Hall Effect Drivers
- **Keypad Backlighting**
  - LED Drivers
  - Boost Converters
  - Schottky Diodes

DIODES INCORPORATED

Strong Relationships Drive LCD/LED TV Product Roadmaps

- **LCD Display Buffer**
  40V High-gain BJT
- **System Power Conversion**
  Low Dropout Regulators
  DC-DC Converters
  Voltage References
  Synchronous MOSFET Controllers
  40V/100V SBR and Schottkys
  Bridge Rectifier Diodes
- **LCD LED Backlighting**
  Current Monitors
  400V High-gain NPN BJT
  60V/100V High-gain NPN BJT
  60V/100V N-channel MOSFETS
- **CCFL Backlighting**
  30V Low On-resistance MOSFETs

- **Antenna Tuner**
  DC-DC Converters
  40V Schottkys
- **System Interface**
  USB Power Switches
  Zener and TVS Arrays
- **System Power Management**
  Buck DC-DC Converters
  Low Dropout Regulators
  20V/30V/40V SBR and Schottkys
  30V P-Channel MOSFETs
  30V Low-saturation PNP BJT
- **Audio Amplifier**
  Buck DC-DC Converters
  Schottky Diodes
  SBR

DIODES INCORPORATED

Product Breadth and Performance for Computing Platforms

- **LCD / LED Backlighting**
  - LED Drivers
  - Boost Converters
  - Schottky Diodes
- **System Voltage Conversion**
  - Low Dropout Regulators
  - DC-DC Converters
  - Schottky Diodes
  - Low-Saturation BJT
- **Battery Power Management**
  - Current Monitors
  - Load Switches
  - Low-Saturation BJT
  - ZXMP series MOSFETs
- **Open / Close Detection**
  - Hall Effect Sensors
  - Hall Effect Drivers

- **Audio Amplifer**
  - Buck DC-DC Converters
  - Schottky Diodes
  - Super Barrier Rectifiers
- **Wireless Connectivity**
  - DC-DC Converters
  - Low Dropout Regulators
- **System Power Management**
  - Buck DC-DC Converters
  - Low Dropout Regulators
  - Super Barrier Rectifiers
  - Schottky Diodes
  - P-Channel MOSFETs
  - Low-Saturation BJT
- **System Interface**
  - USB Power Switches
  - Zener and TVS Arrays

DIODES INCORPORATED

Diodes Leadership in General Illumination

- **Automotive**
  - DRL
  - Tail Light
  - Indicator
  - Headlamp
  - Interior lighting
- **Street Lighting**
  - Street lighting
  - Security lighting
  - Sign Illumination

- **Interior Lighting**
  - MR11, MR16
  - Fluorescent
  - Tube replacement
  - Mood Lighting
- **Flashlight**

	ZXLD series	AP880x series	ZXS series	MOSFET	Low Saturation BJT	Gate Drive Bipolar	Schottky Diode	SBR	Zener Diode	Current Monitor	Low Voltage Reference	Gate Drivers	Linear LED driver
Automotive	✓			✓	✓		✓	✓	✓	✓	✓		
Interior Lighting	✓	✓		✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
Street Lighting	✓	✓		✓	✓	✓	✓	✓	✓	✓	✓	✓	
Flashlight			✓		✓		✓	✓	✓	✓	✓		

Broad and Diverse High-Volume Product Offering

Discrete

Diodes
- Schottky Diodes
- Zener Diodes
- Switching Diodes
- SBR Diodes
- Varactor Diodes
- Power Zener Diodes
- Power Rectifier Diodes

Rectifiers
- Schottky Rectifiers
- Super Barrier Rectifiers
- Standard Rectifiers
- Fast Recovery Rectifiers
- Bridge Rectifiers

MOSFETs
- Small Signal MOSFETs
- Power MOSFETs
- Protected MOSFETs
- High Voltage MOSFETS
- Complementary Pairs
- H-Bridges
- IntelliFET

Protection Devices
- Zener TVS
- Thyristor Surge Protection
- Data Line Protection

Bipolar Transistors
- Small Signal BJT
- Pre-biased BJT
- Medium Power BJT
- High Power BJT
- Darlington Transistors
- Gate-Drivers
- Low Saturation BJT
- H-Bridges

Function Specific Arrays
- Relay Drivers
- Discrete Load Switches
- Discrete Voltage Regulators
- MOSFET Gate-Drivers

Standard ICs

Standard Linear ICs

Linear Voltage Regulators
- Standard Linear Regulators
- Quasi Low Dropout Regulators
- Low Dropout Regulators

Voltage References
- Shunt References
- Micropower References

Current Monitors
- Current Output
- Voltage Output

Operational Amplifiers

Comparators

Special Functions
- Timer IC
- Reset Generators
- Siren Drivers
- Low Power Motor Control
- Current Mirror

Standard Logic ICs
- Single Gate
- Enhanced Single Gate

ASSP

Power Management ICs

DC-DC Switching Regulators
- Buck
- Boost
- Buck/Boost/Inverter

Power Switches
- Load Switches
- USB Switches

LED Drivers
- Charge Pump
- Boost
- Buck

Power Supply
- MOSFET Controllers
- Active OR-ing Controllers
- Chargers

Sensors
- Unipolar Hall Switches
- Bipolar Hall Latches
- Omnipolar Hall Switches
- Smart Fan Drivers
- Temperature Sensors
- Magnetic Sensors

Digital Broadcast by Satellite
- Fixed Bias Generators
- Switched Bias Generators
- Multiplex Controllers
- Integrated Switch Matrix
- DBS Interface

Audio
- Direct Digital Feedback Amplifiers
- Analog Input Amplifiers

DIODES INCORPORATED

Process Expertise for Cost Optimization

Diodes' process expertise drives capability and cost optimized solutions

- Process simplification → Reduced number of silicon layers with equivalent performance
- Process extension for portfolio expansion → Voltage extensions for MOS and Bipolar processes
- Process performance enhancement → State-of-the-art high density trench process for reduced on-resistance
- Unique process capability → Lateral components embedded in power-efficient planar processes

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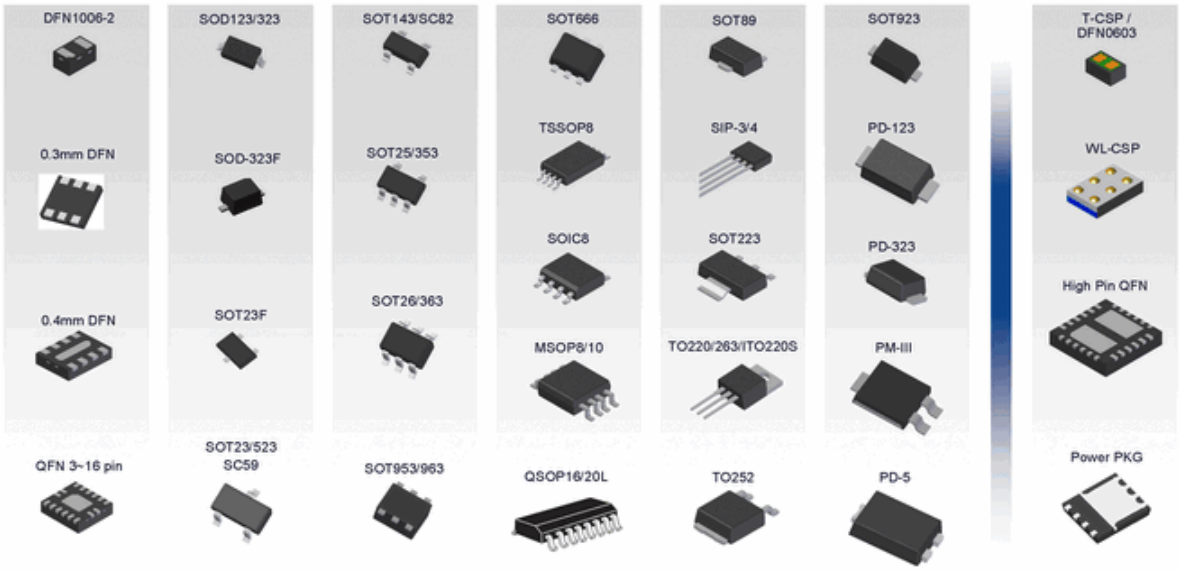
Packaging Focus: Miniaturization and Power Efficiency

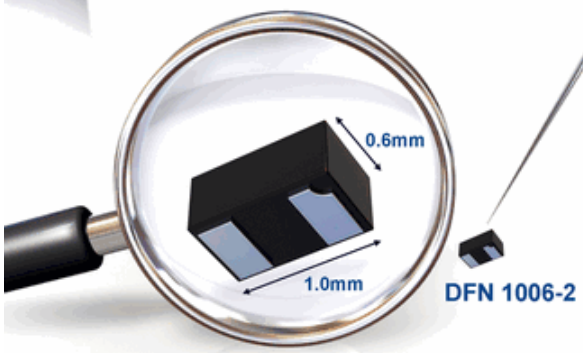


DIODES INCORPORATED

Packaging Focus: Miniaturization and Power Efficiency

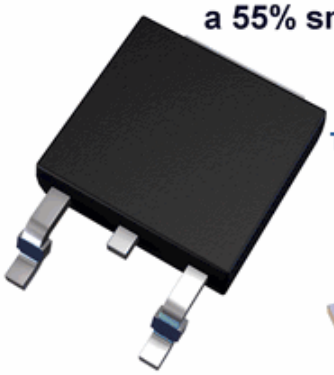
Miniaturization

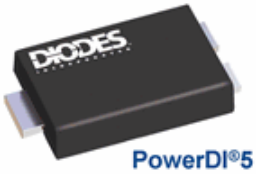
DFN 1006-2 Probably the smallest Discrete semiconductor package.



Power Efficiency

Compared to a TO252, the PowerDI®5 package delivers twice the power density from a 55% smaller footprint.





DIODES INCORPORATED

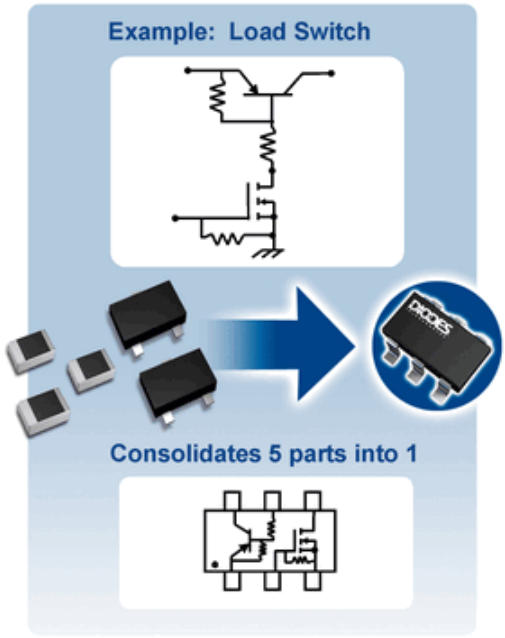
ASMCC: Application-Specific Multi-Chip Circuits

Marrying Silicon Expertise with Packaging Leadership

- Application-tailored component characteristics
- Outstanding at-speed performance
- Current-carrying capability
- Space- and cost-efficient system solutions

ASMCC Portfolio Includes:

- Gate Drivers
- Synchronous Controllers
- LED Drivers
- Load Switches
- Standard Arrays
- Function-specific Arrays



Efficient Manufacturing + Superior Processes

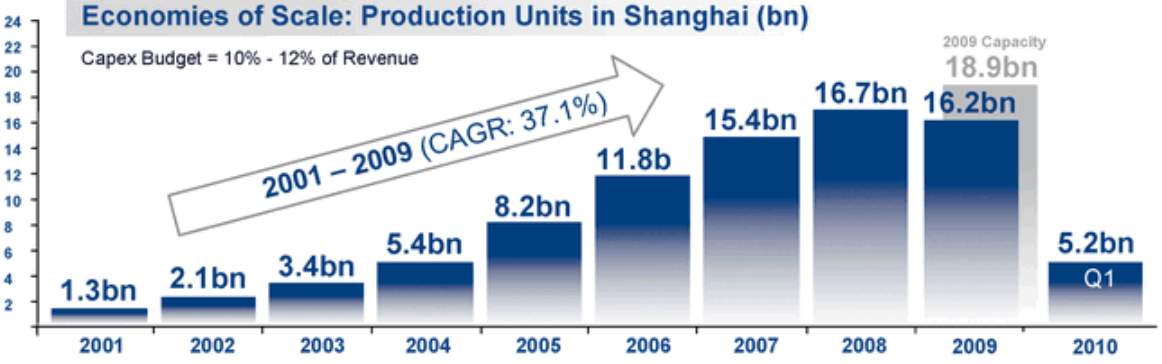
Packaging

- Shanghai-based packaging with capacity greater than 18 billion units
- Flexible and optimized manufacturing process = low packaging cost
- Additional packaging facilities in Neuhaus, Germany and JV in Chengdu, China

Wafer Fab

- Bipolar process technology for discrete and ICs
- High volume 5" and 6" wafer fab in Kansas City, MO for discretes
- 6" Wafer fab in Oldham, UK
- Strong engineering capabilities

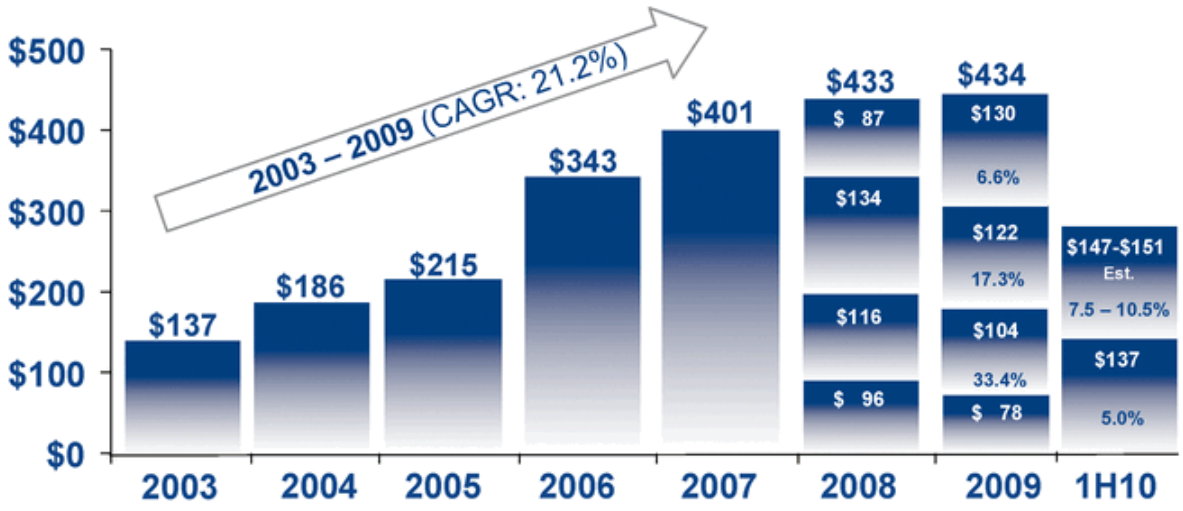
Economies of Scale: Production Units in Shanghai (bn)



Collaborative Customer Relationships

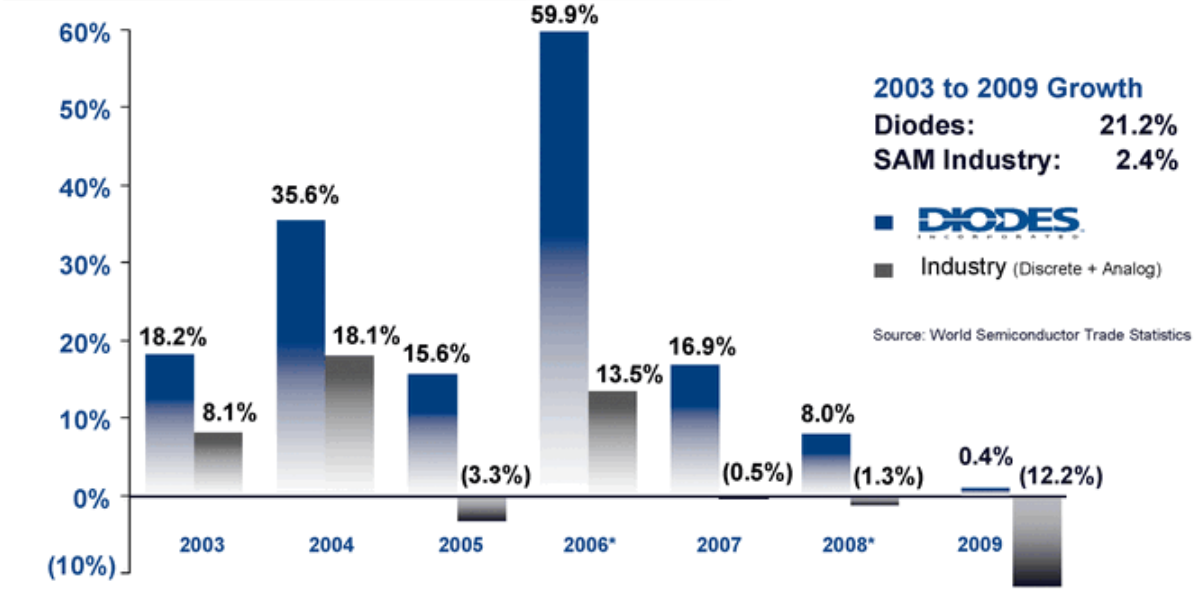
Revenue Growth

Revenue by Year ($M)



Outperforming the Industry

Annual Revenue Growth Rates



2003 to 2009 Growth

Diodes: 21.2%

SAM Industry: 2.4%

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Industry (Discrete + Analog)

Source: World Semiconductor Trade Statistics

*Acquisition Years

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Industry and Media Recognition

NASDAQ Global Select / S&P SmallCap 600 Index / Russell 3000 Index

2009

Forbes' 2009 List of 200 Best Small Companies
Deloitte List of 50 Fastest Growing Tech Companies in Texas – Ranking 49th
Dallas Tech Titans Fastest Growing Technology Companies – Ranking 30th

2008

Forbes' 2008 List of 200 Best Small Companies – Ranking 30th in sales, 49th in EPS growth
Standard and Poor's Global Challenger's 300 List
Business 2.0 Magazine's List of 100 Fastest Growing Technology Companies – Ranking 40th
Forbes' List of 25 Fastest Growing Tech Companies – Ranking 22nd

2007

Forbes' 2007 List of 200 Best Small Companies – Ranking 16th, up from 37th 2nd in EPS growth
BusinessWeek's List of 100 Hot Growth Companies – Ranking 49th
Business 2.0 Magazine's List of 100 Fastest Growing Technology Companies – Ranking 39th

2006

Forbes' 2006 List of 200 Best Small Companies – Ranking 37th
Standard and Poor's Top 300 Growth Companies – Ranking 51st
Fortune's 100 Fastest-Growing Companies – Ranking 82nd
Business 2.0 Magazine's Fastest-Growing Technology Companies – Ranking 26th, up from 45th
BusinessWeek's List of 100 Best Small Companies – Ranking 52nd

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First Quarter 2010 Financial Performance

$M	1Q09	4Q09	1Q10	Y/Y	Q/Q
Revenue	$78	$130	$137	$59	$7
Revenue Growth	(10%)	7%	5%	76%	5%
Gross Profit	$14	$42	$48	$34	$6
Gross Margin %	18.6%	32.1%	34.9%	1630 bp	280 bp
Operating Profit	($8)	$14	$19	$27	$5
Net Income	($11)	$14	$15	$26	$1
Earning per Share	($0.26)	$0.32	$0.33	$0.59	$0.01
Cash Flow from Operations	$7	$22	$24	$17	$2
EBITDA	$3	$25	$33	$30	$8

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Balance Sheet

$M	Dec 31, 2008 (adjusted)	Dec 31, 2009	March 31, 2010
Cash	$104	$242	$248
S-T Investment	$ -	$297	$238
Inventory	$ 99	$ 90	$ 94
L-T Investment	$321	$ -	$ -
Total Assets	$891	$1,018	$982
Current Liabilities	$ 87	$392	$345
L-T Debt	$373	$125	$126
Total Liabilities	$491	$567	$522
Total Equity	$400	$451	$460

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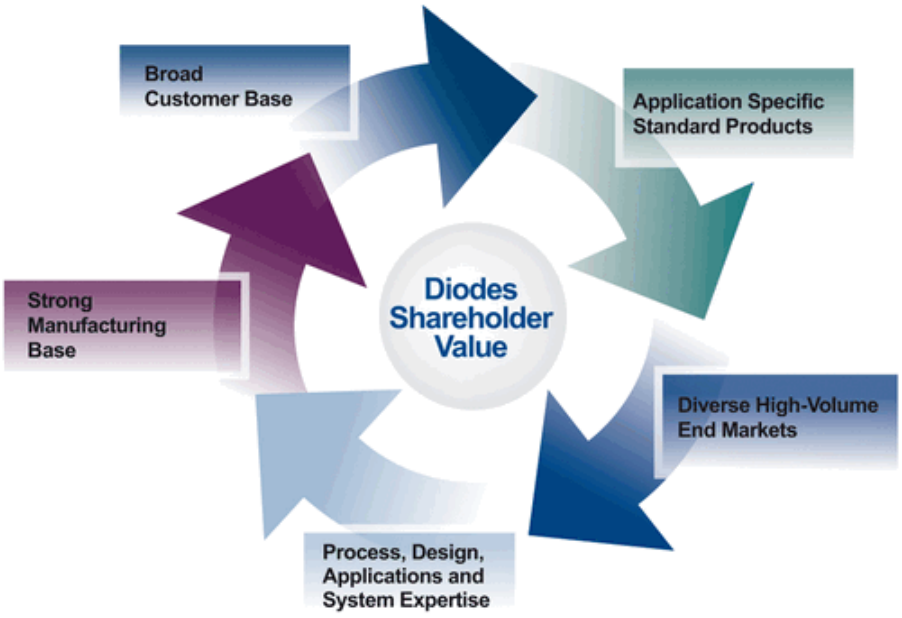
Second Quarter 2010 Updated Guidance

- Revenue expected to range between $147-$151 million, up 7.5% to 10.5% sequentially – Record Revenue
- Gross profit is expected to increase at a rate better than our revenue growth – Record Gross Profit
- Gross profit margin is expected to range between 35% to 36% – Record Gross Margin

Investment Highlights



Thank you

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